

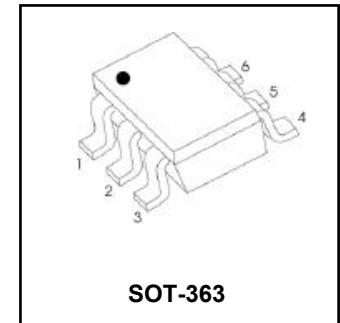
Dual Bias Resistor Transistors

NPN and PNP Silicon Surface Mount
Transistors with Monolithic Bias
Resistor Network

MMUN5311DW
Series

The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. These digital transistors are designed to replace a single device and its external resistor bias network. The BRT eliminates these individual components by integrating them into a single device. In the MMUN5311DWseries, two complementary BRT devices are housed in the SOT-363 package which is ideal for low power surface mount applications where board space is at a premium.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- We declare that the material of product compliance with RoHS requirements.

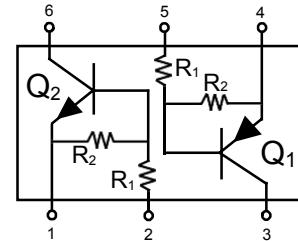


SOT-363

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted, common for Q 1

and Q 2, – minus sign for Q 1 (PNP) omitted)

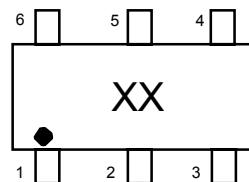
Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc



THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation	P_D	187 (Note 1.)	mW
$T_A = 25^\circ\text{C}$		256 (Note 2.)	
Derate above 25°C		1.5 (Note 1.) 2.0 (Note 2.)	$\text{mW}/^\circ\text{C}$
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation	P_D	250 (Note 1.)	mW
$T_A = 25^\circ\text{C}$		385 (Note 2.)	
Derate above 25°C		2.0 (Note 1.) 3.0 (Note 2.)	$\text{mW}/^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	670 (Note 1.) 490 (Note 2.)	$^\circ\text{C}/\text{W}$
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation	P_D	250 (Note 1.)	mW
$T_A = 25^\circ\text{C}$		385 (Note 2.)	
Derate above 25°C		2.0 (Note 1.) 3.0 (Note 2.)	$\text{mW}/^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	493 (Note 1.) 325 (Note 2.)	$^\circ\text{C}/\text{W}$
Thermal Resistance – Junction-to-Lead	$R_{\theta JL}$	188 (Note 1.) 208 (Note 2.)	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

MARKING DIAGRAM



xx = Device Marking
(See Page 2)

DEVICE MARKING INFORMATION

See specific marking information in the device marking table on page 2 of this data sheet.

1. FR-4 @ Minimum Pad 2. FR-4 @ 1.0 x 1.0 inch Pad

ORDERING, SHIPPING, DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1(K)	R2(K)	Shipping
MMUN5311DW	SOT-363	11	10	10	3000/Tape&Reel
MMUN5312DW	SOT-363	12	22	22	3000/Tape&Reel
MMUN5313DW	SOT-363	13	47	47	3000/Tape&Reel
MMUN5314DW	SOT-363	14	10	47	3000/Tape&Reel
MMUN5315DW	SOT-363	15	10	Ğ	3000/Tape&Reel
MMUN5316DW	SOT-363	16	4.7	Ğ	3000/Tape&Reel
MMUN5330DW	SOT-363	30	1	1	3000/Tape&Reel
MMUN5331DW	SOT-363	31	2.2	2.2	3000/Tape&Reel
MMUN5332DW	SOT-363	32	4.7	4.7	3000/Tape&Reel
MMUN5333DW	SOT-363	33	4.7	47	3000/Tape&Reel
MMUN5334DW	SOT-363	34	22	47	3000/Tape&Reel
MMUN5335DW	SOT-363	35	2.2	47	3000/Tape&Reel

ELECTRICAL CHARACTERISTICS

(TA = 25°C unless otherwise noted, common for Q₁ and Q₂, – minus sign for Q₁ (PNP) omitted) (Continued)

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted, common for Q_1 and Q_2 , – minus sign for Q_1 (PNP) omitted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Base Cutoff Current ($V_{CB} = 50 \text{ V}$, $I_E = 0$)	I_{CBO}	–	–	100	nAdc
Collector-Emitter Cutoff Current ($V_{CE} = 50 \text{ V}$, $I_B = 0$)	I_{CEO}	–	–	500	nAdc
Emitter-Base Cutoff Current ($V_{EB} = 6.0 \text{ V}$, $I_C = 0$)	I_{EBO}	–	–	0.5	mAdc
MMUN5311DW		–	–	0.2	
MMUN5312DW		–	–	0.1	
MMUN5313DW		–	–	0.2	
MMUN5314DW		–	–	0.9	
MMUN5315DW		–	–	1.9	
MMUN5316DW		–	–	4.3	
MMUN5330DW		–	–	2.3	
MMUN5331DW		–	–	1.5	
MMUN5332DW		–	–	0.18	
MMUN5333DW		–	–	0.13	
MMUN5334DW		–	–	0.2	
MMUN5335DW		–	–	–	Vdc
Collector-Base Breakdown Voltage ($I_C = 10 \mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	50	–	–	Vdc
Collector-Emitter Breakdown Voltage (Note 3) ($I_C = 2.0 \text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	50	–	–	Vdc

3. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

ALL MMUN5311DW1T1G SERIES DEVICES

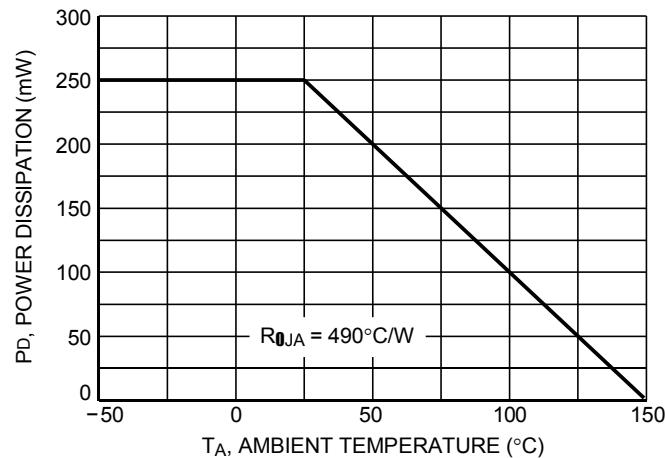


Figure 1. Derating Curve

TYPICAL ELECTRICAL CHARACTERISTICS – MMUN5311DW NPN TRANSISTOR

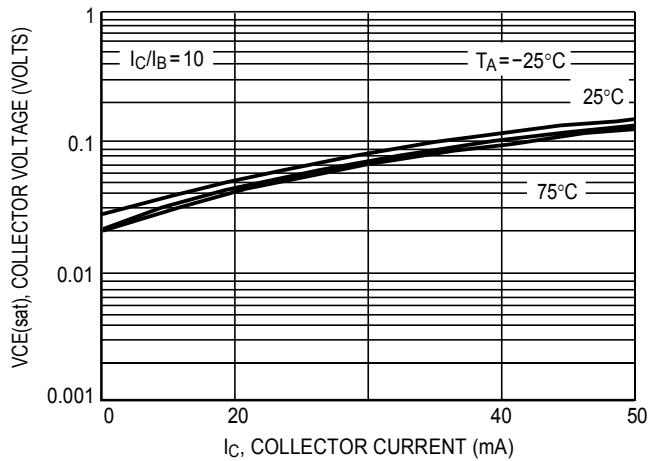


Figure 2. $V_{CE(\text{sat})}$ versus I_C

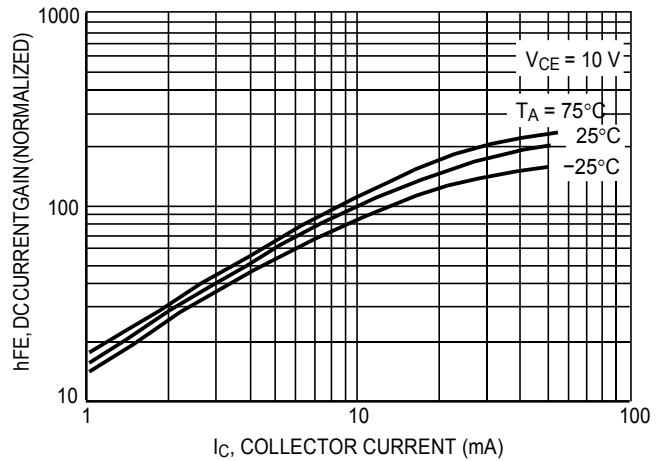


Figure 3. DC Current Gain

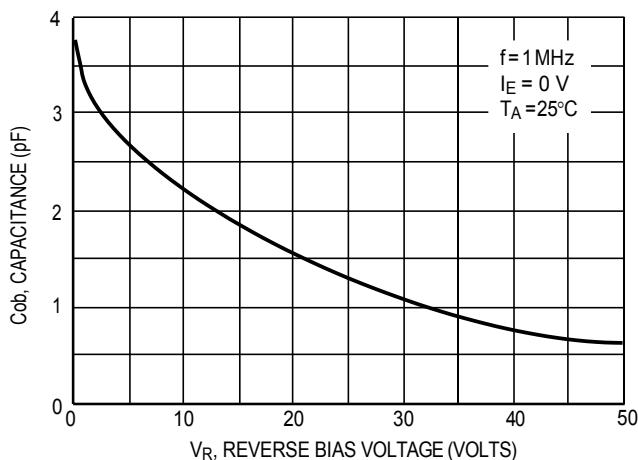


Figure 4. Output Capacitance

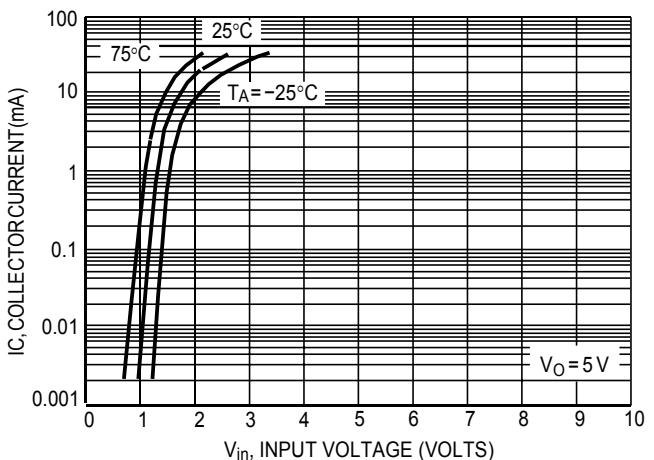


Figure 5. Output Current versus Input Voltage

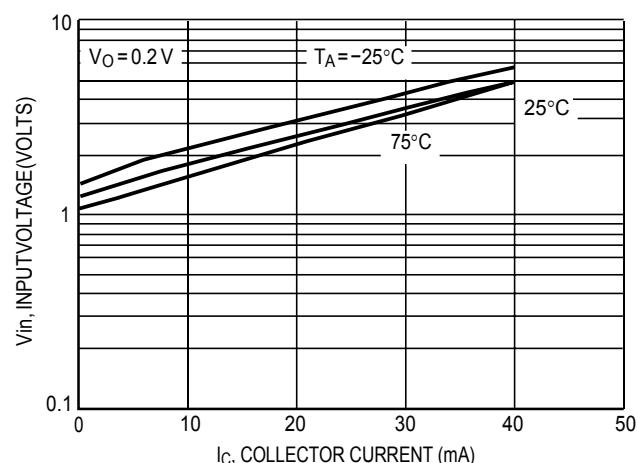


Figure 6. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – MMUN5311DW PNP TRANSISTOR

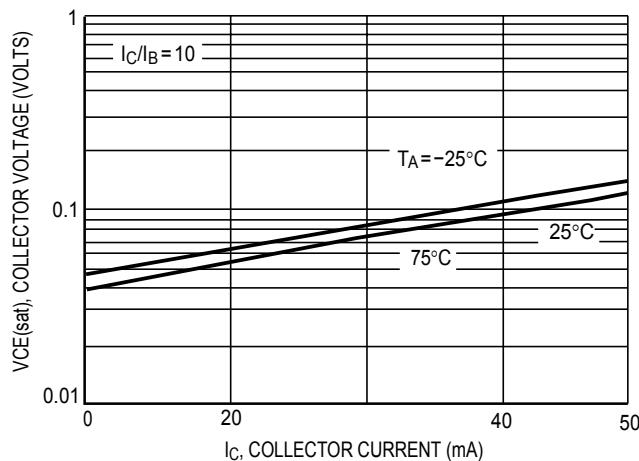


Figure 7. $V_{CE(sat)}$ versus I_C

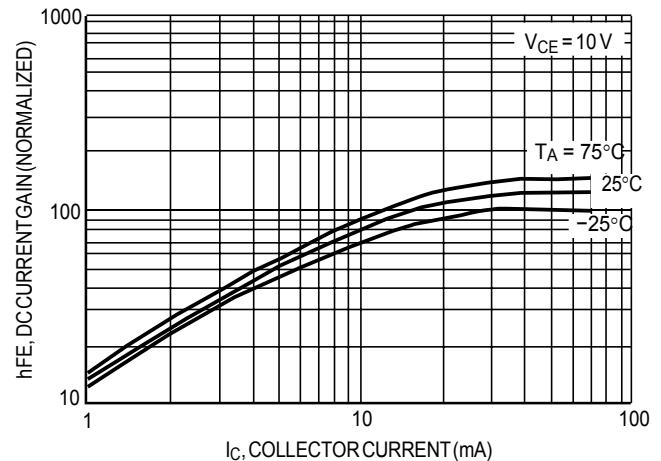


Figure 8. DC Current Gain

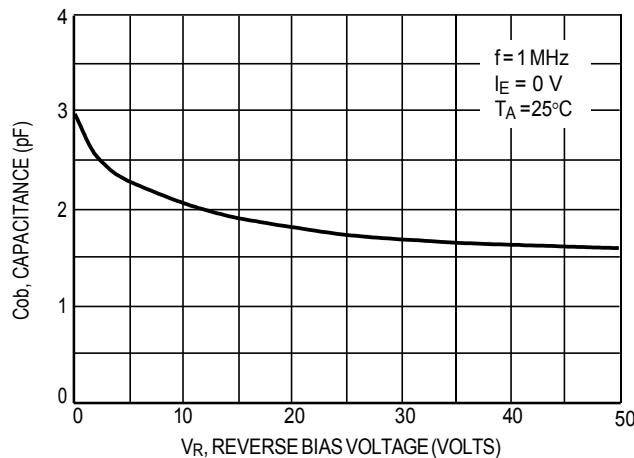


Figure 9. Output Capacitance

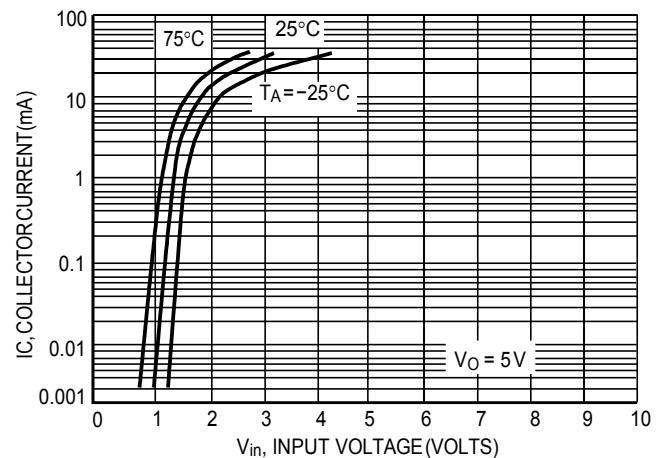


Figure 10. Output Current versus Input Voltage

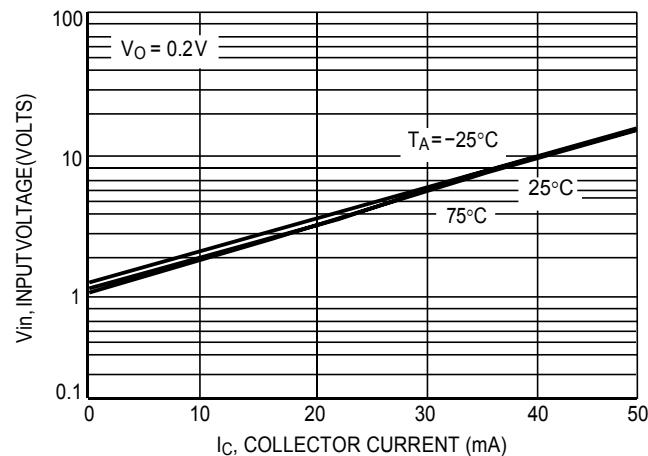


Figure 11. Input Voltage versus Output Current

SOT-363 Package Outline Dimensions

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - Pre-Biased category:

Click to view products by Hong Kong Chuangji manufacturer:

Other Similar products are found below :

[DRC9A14E0L](#) [DTA124GKAT146](#) [DTA144WETL](#) [DTA144WKAT146](#) [DTC113EET1G](#) [DTC115TETL](#) [DTC115TKAT146](#)
[DTC144VUAT106](#) [MUN5241T1G](#) [BCR158WH6327XTSA1](#) [SMUN5330DW1T1G](#) [RN1306\(TE85L,F\)](#) [EMH15T2R](#) [NSBC143ZPDP6T5G](#)
[DTC114EUA-TP](#) [SMUN5237DW1T1G](#) [SMUN5213DW1T1G](#) [SMUN5114DW1T1G](#) [DTC124ECA-TP](#) [DTA114ECA-TP](#) [DTC113EM3T5G](#)
[NSVMUN5135DW1T1G](#) [NSVMUN2237T1G](#) [NSVDTC143ZM3T5G](#) [SMUN5335DW1T2G](#) [SMUN5216DW1T1G](#) [NSVMUN5316DW1T1G](#)
[NSVMUN5215DW1T1G](#) [NSVMUN5213DW1T3G](#) [NSVIMD10AMT1G](#) [NSVEMC2DXV5T1G](#) [NSVDTC144WET1G](#) [NSVDTC123JET1G](#)
[NSVDTA143EM3T5G](#) [NSVB1706DMW5T1G](#) [NSBC143EDP6T5G](#) [NSBA144wdxv6t1g](#) [DTA115TET1G](#) [NSBC115TDP6T5G](#)
[NSBA113EF3T5G](#) [MUN2235T1G](#) [NSBC143ZDXV6T5G](#) [NSVDTA114EM3T5G](#) [MUN2138T1G](#) [DCX124EUQ-7-F](#) [MUN2141T1G](#)
[DTC144TET1G](#) [MUN2238T1G](#) [SMUN5112DW1T1G](#) [NSVMUN5131T1G](#)